

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

• Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

74F253 Dual 4-Input Multiplexer with 3-STATE Outputs

74F253 Dual 4-Input Multiplexer with 3-STATE Outputs

General Description

FAIRCHILD

SEMICONDUCTOR

Features

Multifunction capability

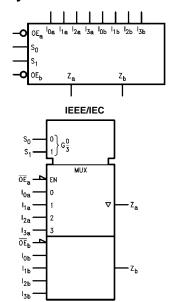
■ Non-inverting 3-STATE outputs

The 74F253 is a dual 4-input multiplexer with 3-STATE outputs. It can select two bits of data from four sources using common select inputs. The output may be individually switched to a high impedance state with a HIGH on the respective Output Enable (\overline{OE}) inputs, allowing the outputs to interface directly with bus oriented systems.

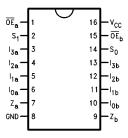
Ordering Code:

| Order Number | Package Number | Package Description |
|------------------------|---------------------------|---|
| 74F253SC | M16A | 16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow |
| 74F253SJ | M16D | 16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide |
| 74F253PC | N16E | 16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide |
| Devices also available | in Tape and Reel. Specify | by appending the suffix letter "X" to the ordering code. |

Logic Symbols



Connection Diagram



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74F253

Unit Loading/Fan Out

| Pin Names | Description | U.L. | Input I _{IH} /I _{IL} | | |
|----------------------------------|---|--------------|---|--|--|
| | Description | HIGH/LOW | Output I _{OH} /I _{OL} | | |
| _{0a} –I _{3a} | Side A Data Inputs | 1.0/1.0 | 20 μA/–0.6 mA | | |
| I _{0b} –I _{3b} | Side B Data Inputs | 1.0/1.0 | 20 µA/–0.6 mA | | |
| S ₀ –S ₁ | Common Select Inputs | 1.0/1.0 | 20 µA/–0.6 mA | | |
| OEa | Side A Output Enable Input (Active LOW) | 1.0/1.0 | 20 µA/–0.6 mA | | |
| OEb | Side B Output Enable Input (Active LOW) | 1.0/1.0 | 20 µA/–0.6 mA | | |
| Z _a , Z _b | 3-STATE Outputs | 150/40(33.3) | –3 mA/24 mA (20 mA) | | |

Functional Description

This device contains two identical 4-input multiplexers with 3-STATE outputs. They select two bits from four sources selected by common Select inputs (S₀, S₁). The 4-input multiplexers have individual Output Enable (\overline{OE}_a , \overline{OE}_b) inputs which, when HIGH, force the outputs to a high impedance (High Z) state. This device is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two select inputs. The logic equations for the outputs are shown below:

$$\begin{split} Z_a &= \overline{OE}_a \bullet (I_{0a} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1a} \bullet \overline{S}_1 \bullet S_0 + \\ & I_{2a} \bullet S_1 \bullet \overline{S}_0 + I_{3a} \bullet S_1 \bullet S_0) \\ Z_b &= \overline{OE}_b \bullet (I_{0b} \bullet \overline{S}_1 \bullet \overline{S}_0 + I_{1b} \bullet \overline{S}_1 \bullet S_0 + \\ & I_{2b} \bullet S_1 \bullet S_0 + I_{3b} \bullet S_1 \bullet S_0) \end{split}$$

If the outputs of 3-STATE devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-STATE devices whose outputs are tied together are designed so that there is no overlap.

| Select Inputs | | | Data I | nputs | Output Enable | Output | | | |
|--|----------------|----------------|----------------|----------------|------------------|--------|---|--|--|
| S ₀ | S ₁ | I ₀ | I ₁ | l ₂ | l ₃ | OE | z | | |
| Х | Х | Х | Х | Х | Х | Н | Z | | |
| L | L | L | Х | Х | Х | L | L | | |
| L | L | н | Х | Х | Х | L | н | | |
| н | L | х | L | Х | Х | L | L | | |
| н | L | х | н | х | х | L | н | | |
| L | н | Х | Х | L | Х | L | L | | |
| L | н | Х | Х | н | Х | L | н | | |
| н | н | х | Х | Х | L | L | L | | |
| н | н | х | Х | Х | н | L | н | | |
| ddress inputs S ₀ and S ₁ are common to both sections. | | | | | | | | | |

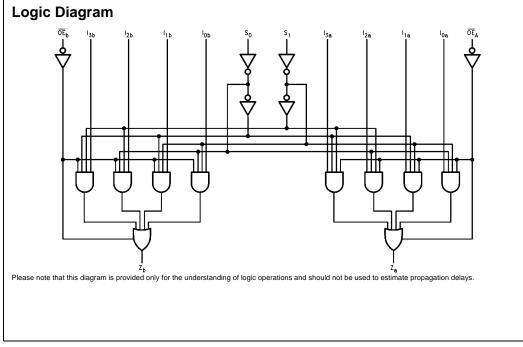
H = HIGH Voltage Level

Truth Table

L = LOW Voltage Level

X = Immaterial

Z = High Impedance



Absolute Maximum Ratings(Note 1)

| Storage Temperature | -65°C to +150°C |
|---|--------------------------------------|
| Ambient Temperature under Bias | -55°C to +125°C |
| Junction Temperature under Bias | -55°C to +150°C |
| V _{CC} Pin Potential to Ground Pin | -0.5V to +7.0V |
| Input Voltage (Note 2) | -0.5V to +7.0V |
| Input Current (Note 2) | -30 mA to +5.0 mA |
| Voltage Applied to Output | |
| in HIGH State (with $V_{CC} = 0V$) | |
| Standard Output | –0.5V to V _{CC} |
| 3-STATE Output | -0.5V to +5.5V |
| Current Applied to Output | |
| in LOW State (Max) | twice the rated I _{OL} (mA) |
| ESD Last Passing Voltage (Min) | 4000V |
| | |

Recommended Operating Conditions

Free Air Ambient Temperature Supply Voltage 74F253

0°C to +70°C +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

| Symbol | Paramete | r | Min | Тур | Max | Units | V _{cc} | Conditions |
|------------------|------------------------------|---------------------|------|------|------|--------|-----------------|------------------------------------|
| V _{IH} | Input HIGH Voltage | | 2.0 | | | V | | Recognized as a HIGH Signal |
| V _{IL} | Input LOW Voltage | | | | 0.8 | V | | Recognized as a LOW Signal |
| V _{CD} | Input Clamp Diode Voltag | e | | | -1.2 | V | Min | I _{IN} = -18 mA |
| V _{OH} | Output HIGH | 10% V _{CC} | 2.5 | | | | | I _{OH} = -1 mA |
| | Voltage | 10% V _{CC} | 2.4 | | | v | Min | I _{OH} = -3 mA |
| | | 5% V _{CC} | 2.7 | | | v | IVIITI | $I_{OH} = -1 \text{ mA}$ |
| | | 5% V _{CC} | 2.7 | | | | | I _{OH} = -3 mA |
| V _{OL} | Output LOW Voltage | 10% V _{CC} | | | 0.5 | V | Min | I _{OL} = 24 mA |
| I _{IH} | Input HIGH | | | | 5.0 | A | Max | V _{IN} = 2.7V |
| | Current | | | | 5.0 | μA | iviax | $v_{IN} = 2.7 v$ |
| I _{BVI} | Input HIGH Current | | | | 7.0 | μA Max | | V - 7 0V |
| | Breakdown Test | | | | 7.0 | μΑ | iviax | V _{IN} = 7.0V |
| ICEX | Output HIGH | | | | 50 | | Maria | V _{OUT} = V _{CC} |
| | Leakage Current | | | | 50 | μA Max | | |
| V _{ID} | Input Leakage | | 4.75 | | | V | 0.0 | I _{ID} = 1.9 μA |
| | Test | | 4.75 | | | v | 0.0 | All Other Pins Grounded |
| I _{OD} | Output Leakage | | | | 3.75 | μA | 0.0 | $V_{IOD} = 150 \text{ mV}$ |
| | Circuit Current | | | | 3.75 | μΑ | 0.0 | All Other Pins Grounded |
| I _{IL} | Input LOW Current | | | | -0.6 | mA | Max | V _{IN} = 0.5V |
| I _{OZH} | Output Leakage Current | | | | 50 | μΑ | Max | $V_{OUT} = 2.7V$ |
| I _{OZL} | Output Leakage Current | | | | -50 | μA | Max | $V_{OUT} = 0.5V$ |
| l _{os} | Output Short-Circuit Current | | -60 | | -150 | mA | Max | $V_{OUT} = 0V$ |
| | | | -100 | | -225 | | | $V_{OUT} = 0V$ |
| I _{ZZ} | Bus Drainage Test | | | | 500 | μA | 0.0V | $V_{OUT} = V_{CC}$ |
| I _{CCH} | Power Supply Current | | | 11.5 | 16 | mA | Max | V _O = HIGH |
| I _{CCL} | Power Supply Current | | | 16 | 23 | mA | Max | $V_0 = LOW$ |
| I _{CCZ} | Power Supply Current | | | 16 | 23 | mA | Max | $V_{\Omega} = HIGH Z$ |

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AC Electrical Characteristics

| Symbol | Parameter | | $T_{A} = +25^{\circ}C$ $V_{CC} = 5.0V$ $C_{L} = 50 \text{ pF}$ | | $T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = 5.0V$ $C_L = 50 \text{ pF}$ | | $T_A = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = 5.0V$ $C_L = 50 \text{ pF}$ | | Units |
|------------------|----------------------------------|-----|--|------|--|------|---|------|-------|
| | | Min | Тур | Max | Min | Max | Min | Max | |
| t _{PLH} | Propagation Delay | 4.5 | 8.5 | 11.5 | 3.5 | 15.0 | 4.5 | 13.0 | ns |
| t _{PHL} | S _n to Z _n | 3.0 | 6.5 | 9.0 | 2.5 | 11.0 | 3.0 | 10.0 | |
| t _{PLH} | Propagation Delay | 3.0 | 5.5 | 7.0 | 2.5 | 9.0 | 3.0 | 8.0 | |
| t _{PHL} | I _n to Z _n | 2.5 | 4.5 | 6.0 | 2.5 | 8.0 | 2.5 | 7.0 | ns |
| t _{PZH} | Output Enable Time | 3.0 | 6.0 | 8.0 | 2.5 | 10.0 | 3.0 | 9.0 | |
| t _{PZL} | | 3.0 | 6.0 | 8.0 | 2.5 | 10.0 | 3.0 | 9.0 | ns |
| t _{PHZ} | Output Disable Time | 2.0 | 3.7 | 5.0 | 2.0 | 6.5 | 2.0 | 6.0 | 115 |
| t _{PLZ} | | 2.0 | 4.4 | 6.0 | 2.0 | 8.0 | 2.0 | 7.0 | |

